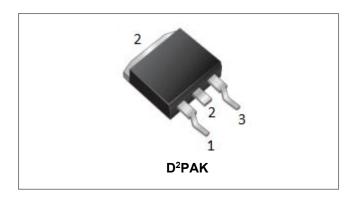


# SDURB15Q60

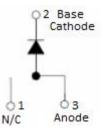
Technical Data Data Sheet N2185, Rev. -



# SDURB15Q60 ULTRAFAST RECTIFIER



### **Circuit Diagram**



### Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

#### **Features**

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>rrm</sub> V <sub>rwm</sub> V <sub>r</sub>	-	600	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=100°C, rectangular wave form	15	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	160	A

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub> @ 15A, Pulse, T <sub>J</sub> = 25°C		1.76	2.0	V
	V <sub>F2</sub>	@ 15A, Pulse, T」= 125°C	1.52	1.7	V
Reverse Current*	$I_{R1}$ @V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25°C		0.2	20	μA
	I <sub>R2</sub>	$@V_R = rated V_{R,} T_J = 125^{\circ}C$	0.03	1	mA
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>m</sub> =250mA 26		40	ns

\* Pulse width < 300 µs, duty cycle < 2%

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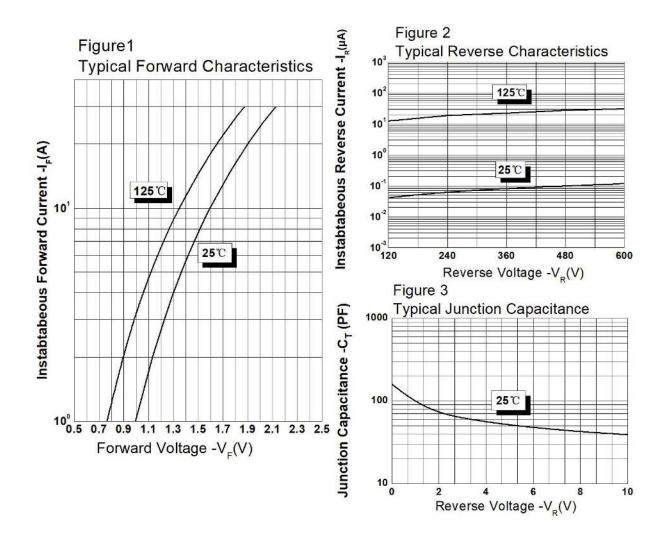


Technical Data Data Sheet N2185, Rev. -

### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Ambient	R <sub>θJA</sub>	DC operation	1.7	°C/W
Approximate Weight	wt	-	1.85	g
Case Style	D <sup>2</sup> PAK			

## **Ratings and Characteristics Curves**





# **SDURB15Q60**



#### **Technical Data** Data Sheet N2185, Rev. -

-E-

**Ordering Information** 

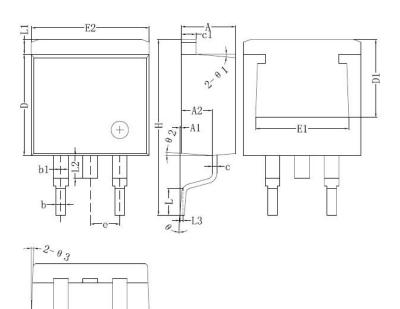
Device

SDURB15Q60

SDURB15Q60TR

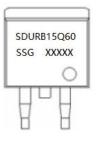
packaging specification.

## Mechanical Dimensions D<sup>2</sup>PAK



Symbol	Dimensions in millimeters				
Symbol	Min.	Typical	Max.		
A	4.47	4.70	4.85		
A1	0	0.10	0.25		
A2	2.59	2.69	2.89		
b	0.71	0.81	0.96		
b1	1.17	1.27	1.37		
с	0.31	0.38	0.61		
c1	1.17	1.27	1.37		
D	8.50	8.70	8.90		
D1	6.40				
E	10.01	10.16	10.31		
E1	7.6				
E2	9.98	10.08	10.31		
е		2.54			
Н	14.6	15.1	15.6		
L	2.00	2.30	2.74		
L1	1.12	1.27	1.42		
L2	1.30		2.20		
L3		0.25BSC			
е	0	-	8°		
e1		5°			
e2		4°			
e3		<b>4</b> °			

## **Marking Diagram**



Where XXXXX is YYWWL

- SDUR = Device Type
  - = Package type = Forward Current (15A)
  - = Q
  - = Reverse Voltage(600V)
  - = SSG = Year

В

15

Q

60

YY

L

WW

SSG

= Week

= Lot Number Cautions: Molding resin

Epoxy resin UL:94V-0

## Carrier Tape Specification D<sup>2</sup>PAK

Package

D<sup>2</sup>PAK

D<sup>2</sup>PAK

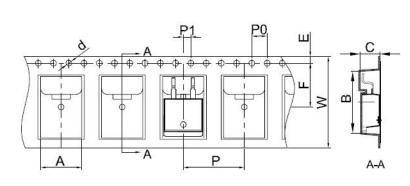
For information on tape and reel specifications, including part

orientation and tape sizes, please refer to our tape and reel

Shipping

800pcs / reel

800pcs / reel



SYMBOL	Millimeters		
	Min.	Max.	
А	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
Е	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

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#### Technical Data Data Sheet N2185, Rev. -

# SDURB15Q60



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